TECHSEM

Y38KPA
PHASE CONTROL THYRISTOR

Features

- Center amplifying gate
- Metal case with ceramic insulator
- Low on-state and switching losses

Typical Applications

- AC controllers
- DC and AC motor control
- Controlled rectifiers

$I_{T(AV)}$ 1550A
V_{DRM}/V_{RRM} 200~600V
I_{TSM} 18 kA
I^2t 1620 10^3A^2S

SYMBOL	CHARACTERISTIC	TEST CONDITIONS		T_j(°C)	VALUE			UNIT
					Min	Type	Max	
$I_{T(AV)}$	Mean on-state current	180° half sine wave 50Hz Double side cooled	T_C=55°C	125			1550	A
			T_C=85°C				1030	
V_{DRM} V_{RRM}	Repetitive peak off-state voltage Repetitive peak reverse voltage	V_{DRM}&V_{RRM} tp=10ms V_{DSM}&V_{RSM}= V_{DRM}&V_{RRM}+100V		125	200		600	V
I_{DRM} I_{RRM}	Repetitive peak current	V_{DM}=V_{DRM} V_{RM}=V_{RRM}		125			40	mA
I_{TSM}	Surge on-state current	10ms half sine wave V_R=0.6V_{RRM}		125			18	kA
I^2t	I^2T for fusing coordination						1620	A^2s*10^3
V_{TO}	Threshold voltage			125			0.76	V
r_T	On-state slop resistance						0.172	mΩ
V_{TM}	Peak on-state voltage	I_{TM}=2000A, F=15kN		125			1.10	V
dv/dt	Critical rate of rise of off-state voltage	V_{DM}=0.67V_{DRM}		125			1000	V/μs
di/dt	Critical rate of rise of on-state current	V_{DM}= 67%V_{DRM} to1300A, Gate pulse t_r ≤0.5μs I_{GM}=1.5A		125			100	A/μs
Q_{rr}	Recovery charge	I_{TM}=1500A,tp=2000μs, di/dt=-20A/μs, V_R =50V		125		1000		μC
I_{GT}	Gate trigger current	V_A=12V, I_A=1A		25	35		300	mA
V_{GT}	Gate trigger voltage				0.8		2.5	V
I_H	Holding current				20		250	mA
V_{GD}	Non-trigger gate voltage	V_{DM}=0.67V_{DRM}		125	0.3			V
$R_{th(j-c)}$	Thermal resistance Junction to case	At 180^0 sine double side cooled Clamping force15kN					0.032	°C /W
$R_{th(c-h)}$	Thermal resistance case to heatsink						0.008	
F_m	Mounting force				10		20	kN
T_{stg}	Stored temperature				-40		140	°C
W_t	Weight					150		g
Outline	KT33aT							

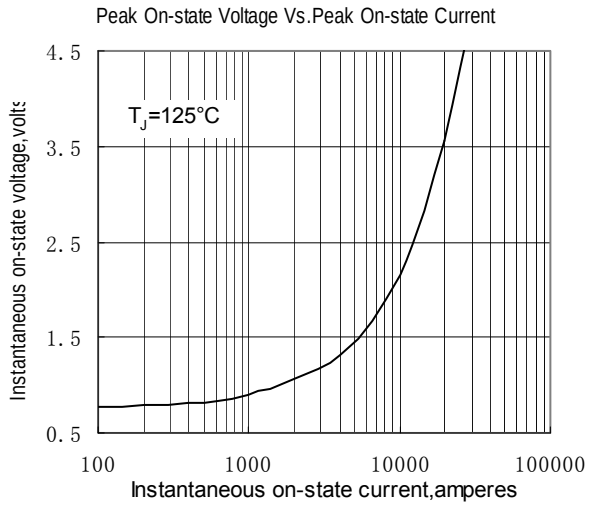

Fig.1

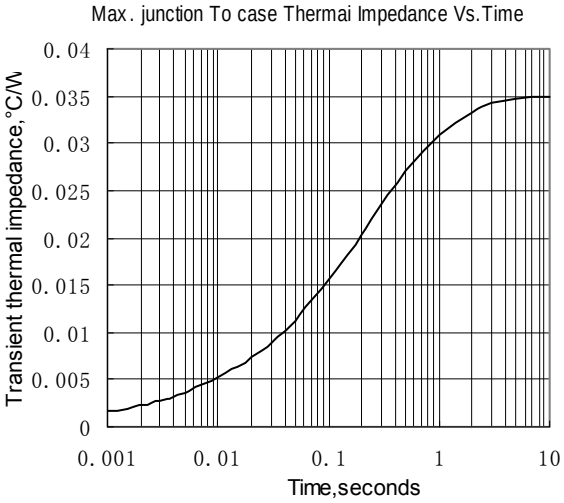

Fig.2

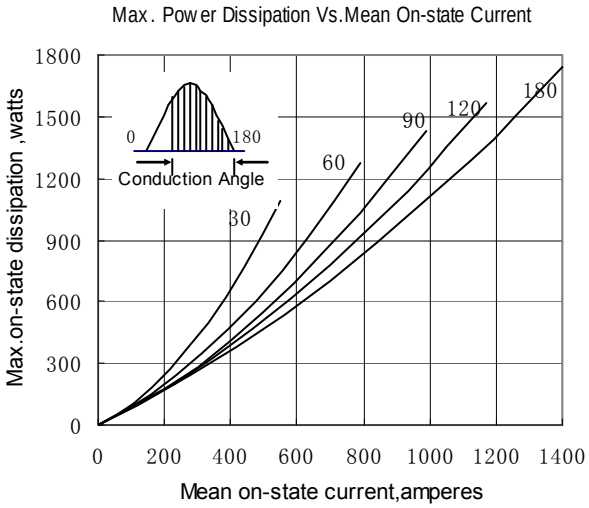

Fig.3

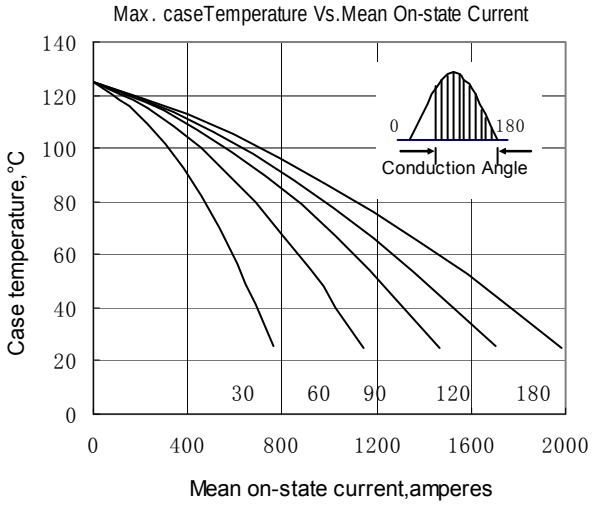

Fig.4

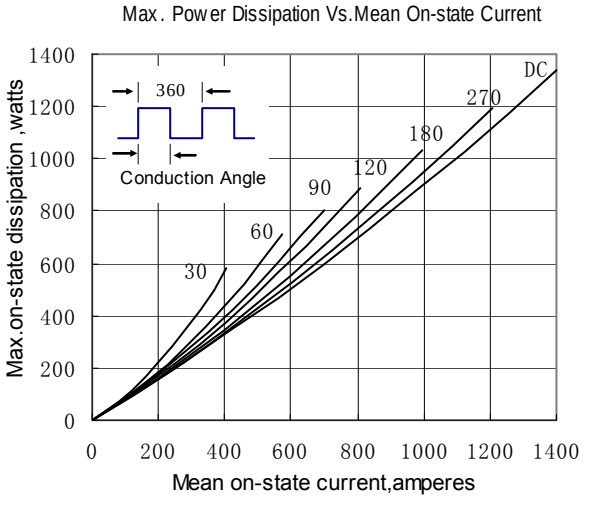

Fig.5

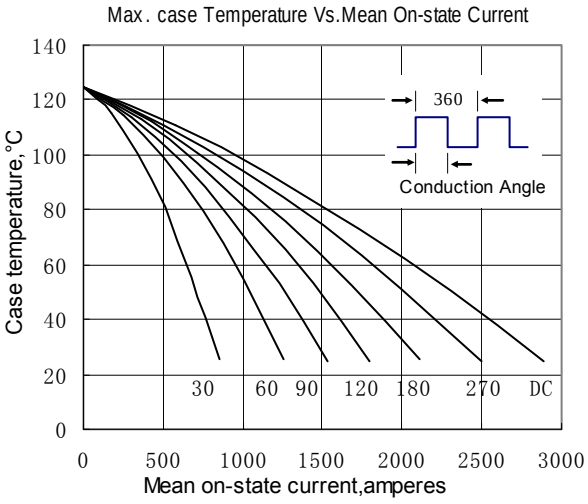

Fig.6

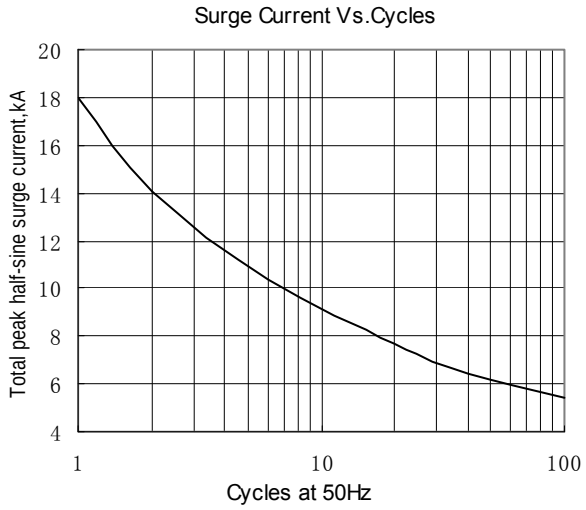

Fig.7

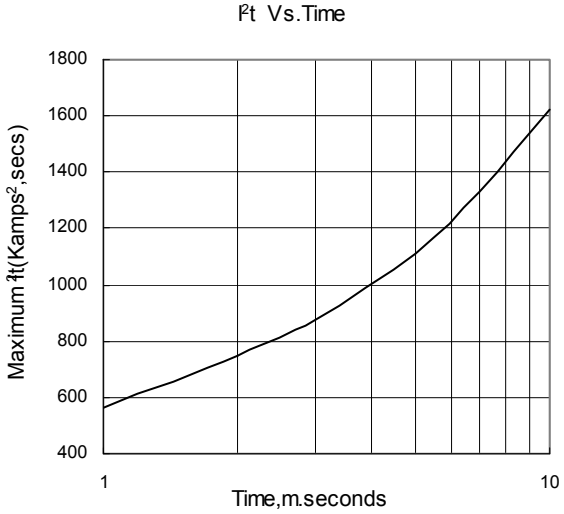

Fig.8

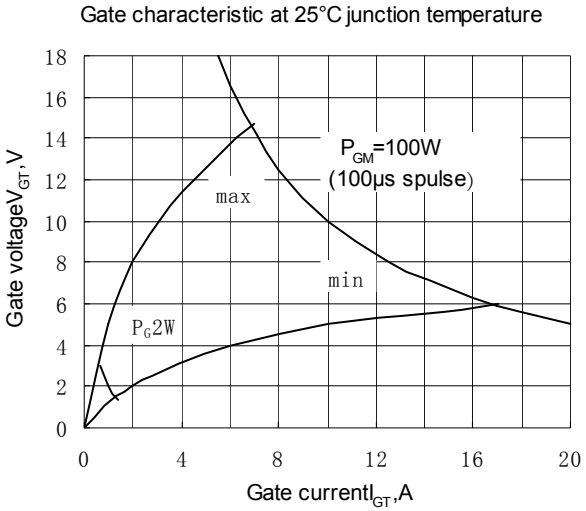

Fig.9

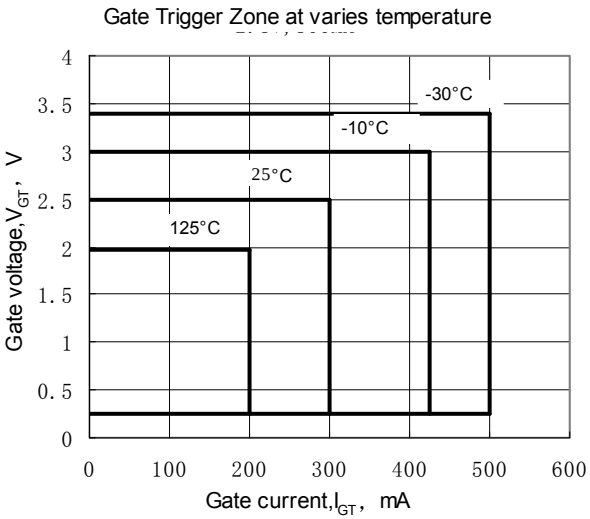

Fig.10

Outline: